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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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# 2SC5954

## Silicon NPN triple diffusion planar type

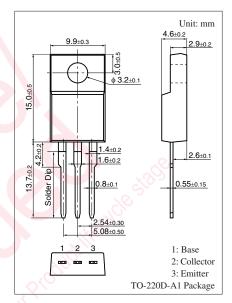
For power amplification with high forward current transfer ratio

#### ■ Features

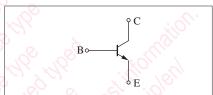
- High forward current transfer ratio h<sub>FE</sub> which has satisfactory linearity.
- ullet Low collector-emitter saturation voltage  $V_{CE(sat)}$
- Full-pack package which can be installed to the heat sink with one screw.

### ■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	$V_{CBO}$	80	V	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	60	V	
Emitter-base voltage (Collector open)	$V_{EBO}$	6	V	
Collector current	$I_{C}$	3	A	
Peak collector current	$I_{CP}$	6	A	
Collector power dissipation	$P_{C}$	25	W	
$T_a = 25$ °C		2.0		
Junction temperature	Tj	150	°C	
Storage temperature	$T_{stg}$	-55 to +150	o +150 °C	



#### Internal Connection



### ■ Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	$V_{CEO}$	$I_C = 10 \text{ mA}, I_B = 0$	60			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 80 \text{ V}, I_{E} = 0$			100	μΑ
Collector-emitter cutoff current (Base open)	$I_{CEO}$	$V_{CE} = 40 \text{ V}, I_{B} = 0$			100	μΑ
Emitter-base cutoff current (Collector open)	$I_{EBO}$	$V_{EB} = 6 \text{ V}, I_{C} = 0$			100	μΑ
Forward current transfer ratio	h <sub>FE1</sub> *	$V_{CE} = 4 \text{ V}, I_{C} = 0.5 \text{ A}$	500		2300	_
N.O.	h <sub>FE2</sub>	$V_{CE} = 4 \text{ V}, I_{C} = 3 \text{ A}$	100			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 1 \text{ A}, I_B = 20 \text{ mA}$			0.6	V
Transition frequency	$f_T$	$V_{CE} = 10 \text{ V}, I_{C} = 0.1 \text{ A}, f = 10 \text{ MHz}$		200		MHz
Turn-on time	t <sub>on</sub>	$I_C = 1$ A, Resistance loaded		0.2		μs
Storage time	t <sub>stg</sub>	$I_{B1} = 0.1 \text{ A}, I_{B2} = -0.1 \text{ A}$		1.5		μs
Fall time	$t_{\rm f}$	$V_{CC} = 50 \text{ V}$		0.1		μs

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

#### 2. \*: Rank classification

Rank	Q	Р
$h_{\mathrm{FE}1}$	500 to 1500	1 300 to 2 300

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